Low Voltage Comparators

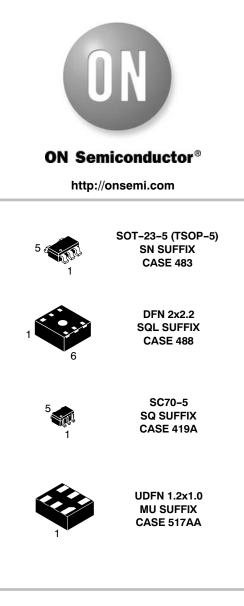
The NCS2200 Series is an industry first sub-one volt, low power comparator family. These devices consume only 10 μ A of supply current. They are guaranteed to operate at a low voltage of 0.85 V which allows them to be used in systems that require less than 1.0 V and are fully operational up to 6.0 V which makes them convenient for use in both 3.0 V and 5.0 V systems. Additional features include no output phase inversion with overdriven inputs, internal hysteresis, which allows for clean output switching, and rail-to-rail input and output performance. The NCS2200 Series is available in the tiny SOT-23-5 and SOT-23-6 package. There are four options featuring two industry standard pinouts. Additionally, the NCS2200 and NCS2202 are available in the SC70-5 package. The NCS2200 is also available in the tiny DFN 2x2.2 package. The NCS2200A is available in UDFN 1.2x1.0 package. (Table 1)

Features

- Operating Voltage of 0.85 V to 6.0 V
- Rail-to-Rail Input/Output Performance
- Low Supply Current of 10 μA
- No Phase Inversion with Overdriven Input Signals
- Glitchless Transitioning in or out of Tri-State Mode
- Complementary or Open Drain Output Configuration
- Internal Hysteresis
- Propagation Delay of 1.1 µs
- Pb-Free Packages are Available

Typical Applications

- Single Cell NiCd/NiMH Battery Powered Applications
- Cellular Telephones
- Alarm and Security Systems
- Personal Digital Assistants



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 13 of this data sheet.

Table 1. Comparator Selector Guide

Output Type	Device	Package	Pinout Style
Complementary	NCS2200SN1T1	SOT-23-5	1
Complementary	NCS2200SN2T1	SOT-23-5	2
Complementary	NCS2200SQ2T2	SC70-5	2
Open Drain	NCS2202SN1T1	SOT-23-5	1
Open Drain	NCS2202SQ1T2	SC70-5	1
Open Drain	NCS2202SN2T1	SOT-23-5	2
Open Drain	NCS2202SQ2T2	SC70-5	2
Complementary	NCS2200SQLT1	DFN, 2x2.2	N/A
Complementary	NCS2200AMUT1	UDFN, 1.2x1.0	N/A

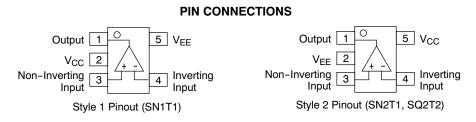
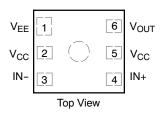
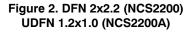


Figure 1. SOT-23-5 (NCS2200, NCS2202), SC70-5 (NCS2200, NCS2202)





MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage Range (V_{CC} to V_{EE})	V _S	6.0	V
Non-inverting/Inverting Input to V _{EE}	-	-0.2 to (V _{CC} + 0.2)	V
Operating Junction Temperature	TJ	150	°C
Operating Ambient Temperature	T _A	-40 to +105	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Output Short Circuit Duration Time (Note 1)	t _S	Indefinite	S
ESD Tolerance (Note 2) NCS2200 Human Body Model Machine Model NCS2202 Human Body Model Machine Model NCS2200A Human Body Model Machine Model	-	2000 200 1000 200 1900 200	V
Thermal Resistance, Junction-to-Ambient TSOP-5 DFN (Note 3) SC70-5 UDFN	R _{θJA}	238 215 283 350	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The maximum package power dissipation limit must not be exceeded.

$$P_{D} = \frac{T_{J(max)} - T_{A}}{R_{\theta,JA}}$$

2. ESD data available upon request.

3. For more information, refer to application note, AND8080/D.

		Ν	ICS2200 Serie	s	
Characteristics	Symbol	Min	Тур	Max	Unit
Input Hysteresis $T_A = 25^{\circ}C$	V _{HYS}	2.0	8.0	20	mV
Input Offset Voltage	V _{IO}				mV
$V_{CC} = 0.85 V$ $T_A = 25^{\circ}C$		-10	0.5	+10	
$T_{A} = -40^{\circ}$ C to 105°C		-12	-	+12	
$V_{CC} = 3.0 V$			0.5		
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		-6.0 -8.0	0.5 -	+6.0 +8.0	
$V_{CC} = 6.0 V$					
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		-5.0 -7.0	0.5	+5.0 +7.0	
Common Mode Voltage Range	V _{CM}	-7.0	- V _{EE} to V _{CC}	+7.0	V
Output Leakage Current (NCS2202) $V_{CC} = 6.0 V$		-	3.3	-	v nA
	I _{LEAK}				
Output Short-Circuit Sourcing or Sinking (V _{out} = GND)	I _{SC}	-	70	-	mA
Common Mode Rejection Ratio V _{CM} = V _{CC}	CMRR	53	65	-	dB
Input Bias Current	I _{IB}	-	1.0	-	pA
Power Supply Rejection Ratio ΔV_{S} = 2.575 V	PSRR	45	55	-	dB
Supply Current V _{CC} = 0.85 V	Icc				μA
$T_A = 25^{\circ}C$		-	10	15	
$T_{A} = -40^{\circ}C \text{ to } 105^{\circ}C$			-	17	
$V_{CC} = 3.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$		_	10	15	
$T_A = -40^{\circ}C$ to $105^{\circ}C$			-	17	
$V_{CC} = 6.0 V$ $T_A = 25^{\circ}C$		_	10	15	
$T_{A} = -40^{\circ}C$ to 105°C			-	17	
Output Voltage High (NCS2200)	V _{OH}				V
$V_{CC} = 0.85 \text{ V}, I_{source} = 0.5 \text{ mA}$ $T_A = 25^{\circ}\text{C}$		V _{CC} - 0.2	V _{CC} - 0.10	_	
$T_{A} = -40^{\circ}$ C to 105°C		V _{CC} - 0.225	-		
$V_{CC} = 3.0 \text{ V}, \text{ I}_{\text{source}} = 3.0 \text{ mA}$			N 0.40		
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		V _{CC} - 0.2 V _{CC} - 0.25	V _{CC} - 0.12 -	-	
V_{CC} = 6.0 V, I _{source} = 5.0 mA					
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		V _{CC} - 0.2 V _{CC} - 0.25	V _{CC} - 0.12	-	
Output Voltage Low	V _{OL}	V(() = 0.23	_		V
$V_{CC} = 0.85 \text{ V}, I_{sink} = 0.5 \text{ mA}$	V OL				v
$T_A = 25^{\circ}C$		-	V _{EE} + 0.10	V _{EE} + 0.2	
$T_A = -40^{\circ}C \text{ to } 105^{\circ}C$ $V_{CC} = 3.0 \text{ V}, I_{sink} = 3.0 \text{ mA}$			-	V _{EE} + 0.225	
$T_A = 25^{\circ}C$		-	V _{EE} + 0.12	V _{EE} + 0.2	
$T_A = -40^{\circ}C$ to $105^{\circ}C$			-	V _{EE} + 0.25	
$V_{CC} = 6.0 \text{ V}, \text{ I}_{sink} = 5.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$		-	V _{EE} + 0.12	V _{EE} + 0.2	
$T_A = -40^{\circ}C$ to $105^{\circ}C$				V _{EE} + 0.25	
Propagation Delay 20 mV Overdrive, $C_L = 15 \text{ pF}$	+_ /		0.7		μs
	t _{PHL} t _{PLH}		0.7 1.1	-	
Output Fall Time V_{CC} = 6.0 V, C_L = 50 pF	t _{FALL}	-	20	-	ns
Output Rise Time V_{CC} = 6.0 V, C _L = 50 pF	t _{RISE}	-	16	-	ns
Powerup Time	t _{PU}	_	35	_	μS

ELECTRICAL CHARACTERISTICS (For all values V_{CC} = 0.85 V to 6.0 V, V_{EE} = 0 V, T_A = 25°C, unless otherwise noted.) (Note 4)

4. The limits over the extended temperature range are guaranteed by design only.

	NCS2200A				
Characteristics	Symbol	Min	Тур	Max	Unit
Input Hysteresis $T_A = 25^{\circ}C$	V _{HYS}	2.0	4.5	20	mV
Input Offset Voltage $V_{CC} = 0.85 \text{ V}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ $V_{CC} = 3.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ $V_{CC} = 6.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$	V _{IO}	-10 -12 -6.0 -8.0 -5.0	0.5 - 0.5 - 0.5	+10 +12 +6.0 +8.0 +5.0	mV
$T_A = -40^\circ C$ to $105^\circ C$		-7.0	-	+7.0	
Common Mode Voltage Range	V _{CM}	-	V_{EE} to V_{CC}	-	V
Output Short-Circuit Sourcing or Sinking (Vout = GND)	I _{SC}	-	60	-	mA
Common Mode Rejection Ratio V _{CM} = V _{CC}	CMRR	53	70	-	dB
Input Bias Current	I _{IB}	-	1.0	-	pА
Power Supply Rejection Ratio ΔV_S = 2.575 V	PSRR	45	80	-	dB
Supply Current $V_{CC} = 0.85 V$ $T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 105^{\circ}C$ $V_{CC} = 3.0 V$ $T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 105^{\circ}C$ $V_{CC} = 6.0 V$ $T_A = 25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } 105^{\circ}C$	Icc	-	7.5 - 8.0 - 9.0 -	15 17 15 17 15 15 17	μΑ
Output Voltage High $V_{CC} = 0.85 \text{ V}, I_{source} = 0.5 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ $V_{CC} = 3.0 \text{ V}, I_{source} = 3.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ $V_{CC} = 6.0 \text{ V}, I_{source} = 5.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$	V _{OH}	$V_{CC} - 0.25 \\ V_{CC} - 0.275 \\ V_{CC} - 0.3 \\ V_{CC} - 0.35 \\ V_{CC} - 0.3 \\ V_{CC} - 0.3 \\ V_{CC} - 0.35 \\ \end{array}$	$V_{CC} = 0.10$ - $V_{CC} = 0.12$ - $V_{CC} = 0.12$ -	-	V
Output Voltage Low $V_{CC} = 0.85 \text{ V}, \text{ I}_{sink} = 0.5 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ $V_{CC} = 3.0 \text{ V}, \text{ I}_{sink} = 3.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ $V_{CC} = 6.0 \text{ V}, \text{ I}_{sink} = 5.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$	V _{OL}		V _{EE} + 0.10 - V _{EE} + 0.12 - V _{EE} + 0.12 -	$V_{EE} + 0.25 \\ V_{EE} + 0.275 \\ V_{EE} + 0.3 \\ V_{EE} + 0.35 \\ V_{EE} + 0.3 \\ V_{EE} + 0.35 \\ \end{array}$	V
Propagation Delay 20 mV Overdrive, $C_L = 15 \text{ pF}$	t _{PHL} t _{PLH}	-	0.5 0.5		μs

 $\textbf{ELECTRICAL CHARACTERISTICS} (For all values V_{CC} = 0.85 V to 6.0 V, V_{EE} = 0 V, T_{A} = 25^{\circ}C, unless otherwise noted.) (Note 5)$

The limits over the extended temperature range are guaranteed by design only.
 Input signal: 1 kHz, squarewave signal with 10 ns edge rate.

Output Fall Time V_{CC} = 6.0 V, C_L = 50 pF (Note 6)

Output Rise Time V_{CC} = 6.0 V, C_L = 50 pF (Note 6)

t_{FALL}

t_{RISE}

_

_

20

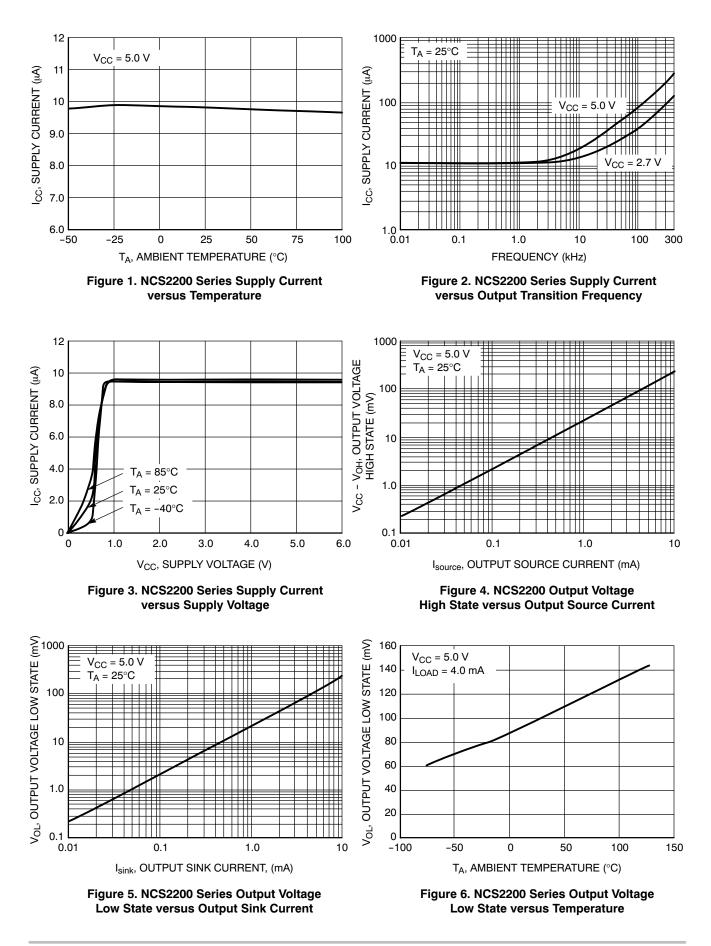
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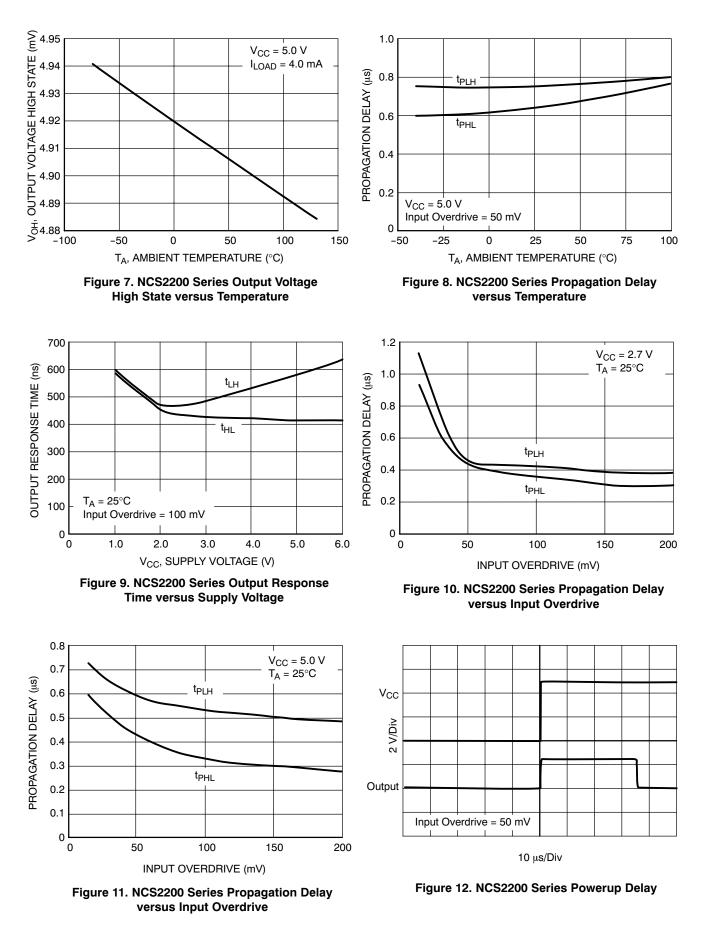
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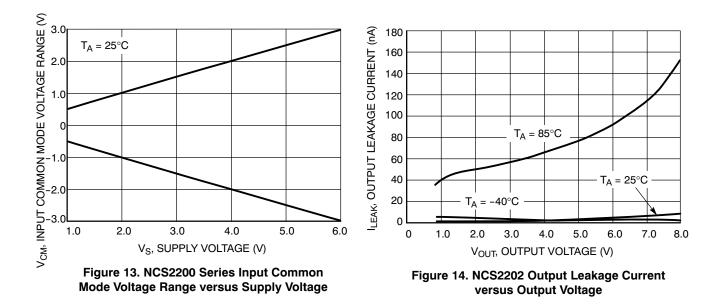
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ns

ns







OPERATING DESCRIPTION

The NCS2200 Series is an industry first sub-one volt, low power comparator family. This series is designed for rail-to-rail input and output performance. These devices consume only 10 μ A of supply current while achieving a typical propagation delay of 1.1 μ s at a 20 mV input overdrive. Figures 10 and 11 show propagation delay with various input overdrives. This comparator family is guaranteed to operate at a low voltage of 0.85 V up to 6.0 V. This is accomplished by the use of a modified analog CMOS process that implements depletion MOSFET devices. The common-mode input voltage range extends 0.1 V beyond the upper and lower rail without phase inversion or other adverse effects. This series is available in the SOT-23-5

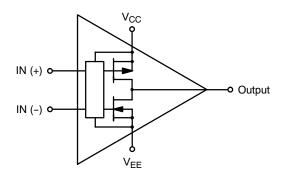


Figure 15. NCS2200SNxT1/NCS2200A Complementary Output Configuration

package. Additionally, the NCS2200 device is available in the tiny DFN 2x2.2 package and the SC70-5 package. NCS2200A is available in UDFN package.

Output Stage

The NCS2200 has a complementary P and N Channel output stage that has capability of driving a rail-to-rail output swing with a load ranging up to 5.0 mA. It is designed such that shoot-through current is minimized while switching. This feature eliminates the need for bypass capacitors under most circumstances.

The NCS2202 has an open drain N-channel output stage that can be pulled up to 6.0 V (max) with an external resistor. This facilitates mixed voltage system applications.

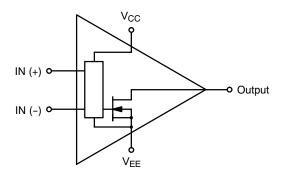
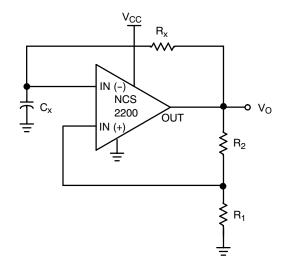


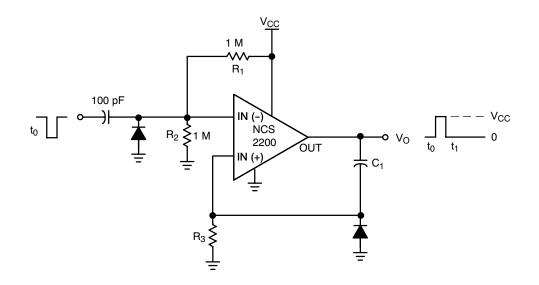
Figure 16. NCS2202SNxT1 Open Drain Output Configuration



The oscillation frequency can be programmed as follows:

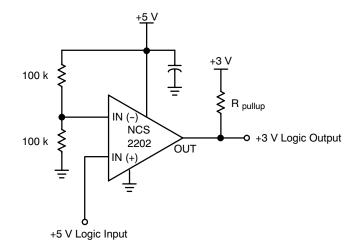
$$f = \frac{1}{T} = \frac{1}{2.2 \text{ R}_X \text{C}_X}$$

Figure 17. Schmitt Trigger Oscillator



The resistor divider R_1 and R_2 can be used to set the magnitude of the input pulse. The pulse width is set by adjusting C_1 and R_3 .

Figure 18. One-Shot Multivibrator



This circuit converts 5 V logic to 3 V logic. Using the NCS2202/3 allows for full 5 V logic swing without creating overvoltage on the 3 V logic input.



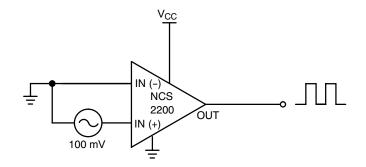


Figure 20. Zero-Crossing Detector

ORDERING INFORMATION

Device	Pinout Style	Output Type	Package	Shipping [†]
NCS2200AMUT1G	N/A	Complementary	UDFN (Pb-Free)	3000 / Tape & Reel
NCS2200SN1T1	1	Complementary	SOT-23-5 (TSOP-5)	3000 / Tape & Reel
NCS2200SN1T1G	1	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2200SN2T1	2	Complementary	SOT-23-5 (TSOP-5)	3000 / Tape & Reel
NCS2200SN2T1G	2	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2200SQ2T2	2	Complementary	SC70-5	3000 / Tape & Reel
NCS2200SQ2T2G	2	Complementary	SC70-5 (Pb-Free)	3000 / Tape & Reel
NCS2200SQLT1	N/A	Complementary	DFN, 2x2.2	3000 / Tape & Reel
NCS2200SQLT1G	N/A	Complementary	DFN, 2x2.2 (Pb-Free)	3000 / Tape & Reel
NCS2202SN1T1	1	Open Drain	SOT-23-5 (TSOP-5)	3000 / Tape & Reel
NCS2202SN1T1G	1	Open Drain	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2202SQ1T2G	1	Open Drain	SC70-5 (Pb-Free)	3000 / Tape & Reel
NCS2202SN2T1	2	Open Drain	SOT-23-5 (TSOP-5)	3000 / Tape & Reel
NCS2202SN2T1G	2	Open Drain	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2202SQ2T2G	2	Open Drain	SC70-5 (Pb-Free)	3000 / Tape & Reel

This device contains 93 active transistors.

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS



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- x = I for NCS2200SN1T1 J for NCS2200SN2T1 M for NCS2202SN1T1 N for NCS2202SN2T1
- A = Assembly Location

Y = Year

- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)





CB = Specific Device Code

N

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code overbar and underbar may vary depending upon manufacturing location.





CBx	=	Specific Device Code
х	=	A for NCS2200SQ2T2
		D for NCS2202SQ1T2G
		E for NCS2202SQ2T2G
М	=	Date Code*

= Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation, position, and underbar may vary depending upon manufacturing location.





(Top View)

- S = Specific Device Code
- M = Date Code
- = Pb-Free Package

PACKAGE DIMENSIONS

SOT-23-5 / TSOP-5 / SC59-5 **SN SUFFIX** PLASTIC PACKAGE CASE 483-02 ISSUE H

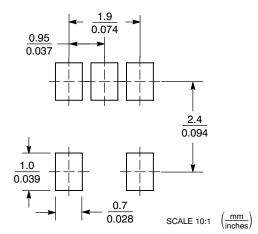
NOTE 5 D 5X 🔶 0.20 C A B 2X 🗀 0.10 T ¥. 2X 🛆 0.20 Т 5 4 в S Å Hil L DETAIL Z G С ΠП SEATING PLANE 0.05 Ť

NOTES:

- NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS
- OF BASE MATERIAL. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. 4.
- 5.
- BUHRS. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIMETERS		
DIM	MIN	MAX	
Α	3.00	BSC	
В	1.50	BSC	
С	0.90	1.10	
D	0.25	0.50	
G	0.95	BSC	
н	0.01	0.10	
J	0.10	0.26	
к	0.20	0.60	
L	1.25	1.55	
м	0 °	10 °	
S	2.50	3.00	

SOLDERING FOOTPRINT*

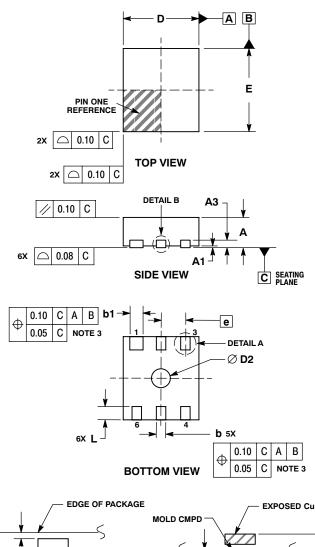


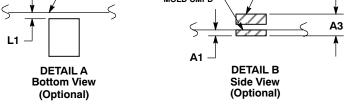
DETAIL Z

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

DFN6, 2x2.2 SQL SUFFIX CASE 488-03 ISSUE G



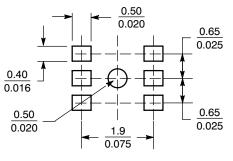


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- 3.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30mm FROM TERMINAL COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS. TERMINAL & MAY HAVE MOLD COMPOUND MATERIAL A ONCO ENCE FROM
- 4. 5.
- MATERIAL ALONG SIDE EDGE. 6. DETAILS A AND B SHOW OPTIONAL VIEWS
- FOR END OF TERMINAL LEAD AT EDGE OF PACKAGE AND SIDE EDGE OF PACKAGE.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.80	0.90	1.00	
A1	0.00	0.03	0.05	
A3		0.20 REF		
b	0.20	0.25	0.30	
b1	0.30	0.35	0.40	
D		2.00 BSC		
D2	0.40	0.50	0.60	
E		2.20 BSC		
е	0.65 BSC			
L	0.30	0.35	0.40	
L1	0.00	0.05	0.10	

SOLDERING FOOTPRINT*

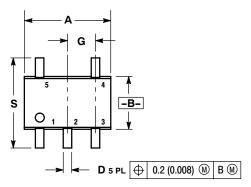


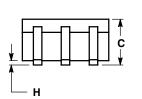
SCALE 10:1

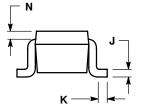
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SC70-5/SC88A (SOT-353) SQ SUFFIX CASE 419A-02 ISSUE J





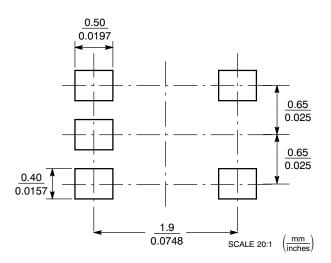


NOTES:

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02. 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
c	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Η		0.004		0.10
Ĺ	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20

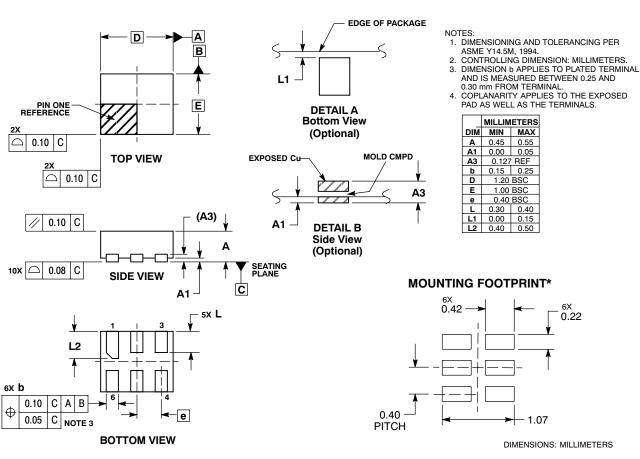
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

UDFN6, 1.2x1.0, 0.4P CASE 517AA-01 ISSUE C



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